

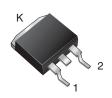
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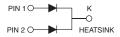
Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance

D²PAK (TO-263AB)



MBRB30HxxCT



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V_{RRM}	45 V, 60 V				
I _{FSM}	150 A				
V _F	0.56 V, 0.59 V				
I _R	80 μΑ, 60 μΑ				
T _J max.	175 °C				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Common cathode				

FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- · Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3_A
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		MBRB30H45CT MBRB30H60C		UNIT		
Maximum repetitive peak reverse voltage		45 60		V		
Working peak reverse voltage		45 60		V		
Maximum DC blocking voltage		45 60		V		
Maximum average forward rectified current (fig. 1) total device per diode		30		Α		
		15				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150		Α		
Peak repetitive reverse surge current per diode at $t_p = 2 \mu s$, 1 kHz		1.0 0.5		Α		
Peak non-repetitive reverse energy (8/20 µs waveform)		25 20		mJ		
Non-repetitive avalanche energy per diode at 25 °C, I _{AS} = 4 A, L = 10 mH		80		mJ		
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω		25		kV		
Voltage rate of change (rated V _R)		10 000		V/µs		
Operating junction and storage temperature range		-65 to +175		°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDITIONS		SYMBOL	MBRB30H45CT		MBRB30H60CT		UNIT	
Maximum instantaneous forward voltage per diode	I _F = 15 A	T _C = 25 °C	V _F ⁽¹⁾	-	0.62	-	0.68	V	
	I _F = 15 A	T _C = 125 °C		0.49	0.56	0.55	0.59		
	I _F = 30 A	T _C = 25 °C		VF (''	-	0.73	-	0.83	v
	I _F = 30 A	T _C = 125 °C		0.62	0.67	0.68	0.71		
Maximum reverse current per diode at working peak reverse voltage		T _J = 25 °C	I _R ⁽²⁾	1	80	-	60	μΑ	
		T _J = 125 °C		5.0	15	4.0	15	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRB	UNIT		
Typical thermal resistance junction to case per diode	$R_{ heta JC}$	1.5	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	MBRB30H45CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB30H45CT-E3/81	1.35	81	800/reel	Tape and reel	
TO-263AB	MBRB30H45CTHE3_B/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MBRB30H45CTHE3_B/I (1)	1.35	I	800/reel	Tape and reel	

Notes

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

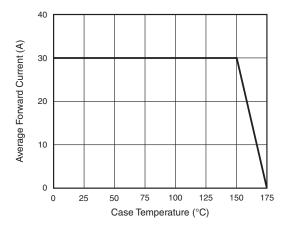


Fig. 1 - Forward Derating Curve

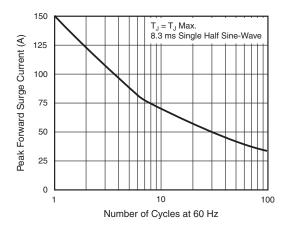


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

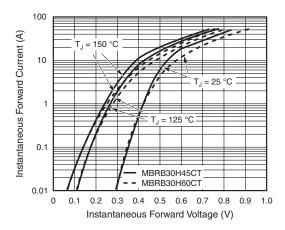


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

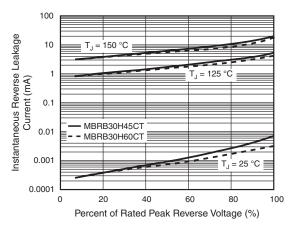


Fig. 4 - Typical Reverse Characteristics Per Diode

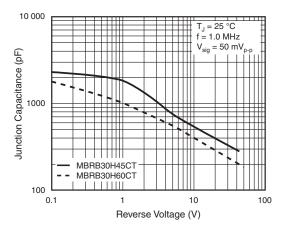


Fig. 5 - Typical Junction Capacitance Per Diode

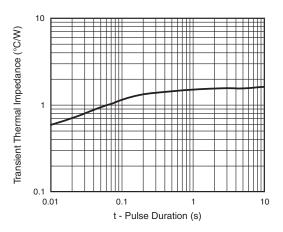


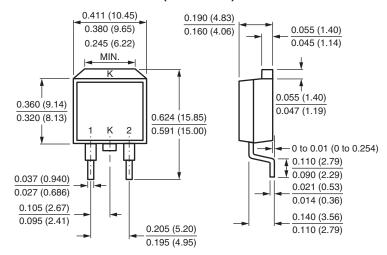
Fig. 6 - Typical Transient Thermal Impedance Per Diode



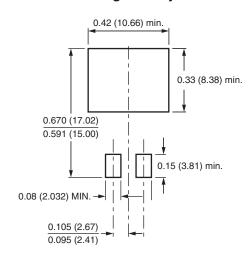
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

D²PAK (TO-263AB)



Mounting Pad Layout



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